OP Series



FEATURES

- Case sizes: 0805 to 2220
- NPO and X7R dielectrics
- Capacitance range: 1pF to 4.7µF
- Designed to significantly minimize the probability of short circuit or low IR failure due to board flexion
- Ag/Pd/Pt, Ni barrier, epoxy terminations available
- RoHS and Non RoHS compliant capacitors available
- Screening in accordance with ESA specifications available

PHYSICAL CHARACTERISTICS

CONSTRUCTION

MLCC capacitors for surface mounting with optional Nickel barrier

MARKING (on request)

Capacitance value code

ELECTRICAL SPECIFICATIONS

Description	NPO	X7R		
Operating temperature	-55°C to +125°C*	-55°C to +125°C*		
Climatic category	55/125/56	55/125/56		
Rated voltage (U _{RC})	$10V_{\text{DC}}$ to $100V_{\text{DC}}$	$10V_{DC}$ to $100V_{DC}$		
Maximum Δ C/°C over temperature range without DC voltage applied	NA	±15%		
Temperature coefficient with or without DC voltage applied	(0±30)ppm/°C	NA		
Dielectric withstanding voltage	2.5 U _{RC}	2.5 U _{RC}		
Capacitance	at 1MHz for C \leq 1,000pF at 1kHz for C $>$ 1,000pF	at 1MHz for C \leq 100pF at 1kHz for C $>$ 100pF		
Dissipation factor at 25°C	≤0.015 (150/C + 7)% at 1MHz for C ≤ 50pF ≤0.15% at 1MHz for 50pF < C ≤ 1,000pF ≤0.15% at 1kHz for C > 1,000pF	≤2.5% at 1MHz for C ≤ 100pF ≤2.5% at 1kHz for C > 100pF		
Insulation resistance at 25°C under U _{RC}	$\geq 100,000 \text{ M}\Omega \text{ for C} \leq 10 \text{nF}$ $\geq 1,000 \text{ M}\Omega.\mu\text{F for C} > 10 \text{nF}$	\geq 100,000 M Ω for C \leq 10nF \geq 1,000 M $\Omega.\mu F$ for C $>$ 10nF		
Aging	None	\leq 2.5% per decade hour		

Other temperature coefficients, temperature characteristics 2B1, BX, BR and Bismuth free dielectrics are available. * Operating temperature up to 250°C available upon request. Contact your sales representative.

HOW TO ORDER

OP	1210	X7R			С		М	F	270nF	10%	50V	S8	T5
Series	Size	Dielectric		Termi	inatio	ו	Marking	Quality level	Capacitance	Tolerance	Rated voltage	Packaging	Reliability level
OP: Open-	0805 1206	NPO X7R		W = RoHS	comp	oliant	 = no marking 	 standard quality level 	Capacitance value in clear	<u>NPO:</u> cap.value≤12pF	10V 16V	 Exxelia packaging 	For F parts only. Acc. to Exxelia
mode	1200	Arn	-	Ag/Pd/Pt	W	Ag/Pd/Pt	M = Marking:		value in cical	±0.25pF	257	S8* = available for 0402 to 1210 sizes.	spec.
	1812		Q	Ag *	QW	Ag	capacitance value coded	F = Hi-Rel quality: screening		cap. value ≤ 8.2pF	50V	S12* = available for	-
	2220		н	Ag/Pd/Pt + dipped	нพ	Ag/Pd/Pt	(from 0805 to 3040	in accordance with		±0.5pF	100V	1812 to 2220 sizes.	T5 T6
			D G YC YD YG * **	Sn/Pb 60/40 Ag + Ni** + electrolytic Sn/Pb 95/5 Ag + Ni*** + electrolytic Sn/Pb 60/40 Ag + Ni + Au Ag + Polymer	3040 2220 n dem 1210	Sn S Ag + Ni + Au Ag + Polymer + Ni + Sn Ag + Polymer + Ni + Au sizes sizes sizes sizes sizes	sizes].	Exxelia specification		$\pm 1pF$ cap. value > 22pF $\pm 1\%$ cap. value > 12pF $\pm 2\%$ cap. value > 8.2pF $\pm 5\%$ $\pm 10\%$ cap. value > 3.9pF $\pm 20\%$ $\frac{X7R.}{\pm 5\%}$ $\pm 10\%$ $\pm 20\%$	Intermediary and higher voltages available on request.	BA* = available for 0402 to 2220 (except 0907) sizes. * not available with H, HW and E, terminations See page 13	See page 15

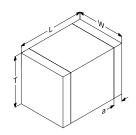


STANDARD

Open Mode Chips Capacitors

OP Series

DIMENSIONS in inches (mm)



L, W, T for tinned chips (H, HW): +0.02" (+0.5mm)

STANDARD RATINGS

	Size	08	05	12	206	12	210	18	312	223	20
	L		± 0.012		± 0.01		±0.016	0.177 ± 0.02		0.224 ± 0.02	
	-	(2 ±	0.3)	(3.2 :	± 0.25)	(3.2	±0.4)	(4.5	± 0.5)	(5.7 ±	0.5)
sions (mm)	w	0.049 :	± 0.008	0.063	± 0.006	0.098	± 0.012	0.126	±0.016	0.197 :	± 0.02
	٧٧	(1.25	± 0.2)	(1.6 :	± 0.15)	(2.5	± 0.3)	(3.2	± 0.4)	(5 ±	0.5)
Dimensions inches (mm)		0.02 ±	0.012	0.02 -	± 0.012	0.024	±0.016	0.024	±0.016	0.024 ±	0.016
ii ii	а	(0.5 :	± 0.3)	(0.5	± 0.3)	(0.6	± 0.4)	(0.6	± 0.4)	(0.6 ±	0.4)
	T max.	0.0)52	0.	063	0.0	071	0.0	071	0.0	79
	i max.	(1	.3)	(1	6)	(1.8)		(1.8)		(2)	
Die	electric	NPO	X7R	NPO	X7R	NPO	X7R	NPO	X7R	NPO	X7R
Min.	Cap.value	1pF	390pF	1pF	1nF	10pF	1nF	47pF	1.8nF	100pF	8.2nF
	10V	5.6nF	270nF	18nF	820nF	27nF	1.5µF	47nF	2.7µF	120nF	4.7µF
J _{RC}]	16V	5.6nF	220nF	18nF	680nF	27nF	1.2µF	47nF	2.2µF	120nF	3.9µF
Rated voltage (U _{RC})	25V	3.3nF	120nF	10nF	330nF	15nF	560nF	27nF	1µF	56nF	2.2µF
ed volt	50V	1.8nF	68nF	4.7nF	150nF	6.8nF	330nF	12nF	680nF	27nF	1.5µF
Rati	63V	1.5nF	39nF	3.9nF	82nF	5.6nF	180nF	10nF	390nF	22nF	820nF
	100V	820pF	18nF	1.8nF	47nF	2.7nF	100nF	5.6nF	180nF	12nF	470nF

Available capacitance values:

NPO: E6, E12, E24, E48, E96 (See page 14). Specific values upon request. X7R: E6, E12, E24 (See page 14). Specific values upon request.

The above table defines the standard products, other components may be built upon request.

Other temperature coefficients, temperature characteristic 2B1 and Bismuth free dielectrics are available: contact your sales representative.



General Information NPO/COG (Class 1)

COMPOSITION

NPO capacitors are produced by using a dielectric made of titanium dioxide (Ti O_2) modified by magnesium oxide Mg O (white ceramics) or a rare earth oxide, e.g. Nd₂ O_3 (other NPO ceramics).

As a consequence, these ceramics are non ferro-electric materials with a low dielectric constant ($\epsilon r \le 110$).

Other additives are used to dope the dielectric constant up to 300. Though derogating from CG class, doped dielectric constant features a linear temperature drift and a matchless stability compared with class 2 ceramics.

The wide range of possible NPO dielectric compositions enables to use the material best suited to the application :

- standard applications,
- high voltage,
- high temperature,
- microwave,
- power capacitors.

«Temperature coefficient» compositions are particularly suitable for impedance matching. These ceramics usually enable to achieve temperature coefficients from 0 to -1000 ppm/°C. For specific requirements, other coefficients can be achieved (e.g. -3300 ppm/°C).

STABILITY

As $\ensuremath{\epsilon} r$ is low, these dielectrics are extremely stable with only minor changes under such stresses as :

- temperature,
- voltage,
- frequency.

In addition, they are not affected by piezo-electric phenomena and their dielectric absorption coefficients are low and even non measurable for dielectrics with the lowest constants.

MECHANICAL PROPERTIES

Class 1 ceramics are the perfect match for metallic electrodes made of Pd or Ag-Pd alloy and have a high hardness and mechanical toughness making them resistant to thermal shocks (wave soldering for instance) and to thermal cycling after mounting on substrates having an expansion coefficient close to the capacitor one.

Ceramic chips meet CECC 32100 and NF C 93133 standards.

CLIMATIC CATEGORIES

Climatic categories are identified by three-digit codes as per NF C 20700 standard. Coding method is described in table 6.

e.g. : - 55°C + 125°C / 56 days category is identified by code 434.

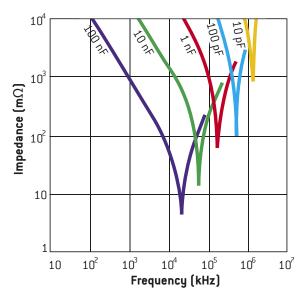
TEMPERATURE COEFFICIENT

Tempe	erature coefficient k $ heta(ppr$	n/°C)		
kθ	Tolerances	Code letter		
+ 100	± 30	AG		
0	± 30	CG		
- 33	± 30	HG		
- 75	± 30	LG		
- 150	± 30	PG		
- 220	± 30	RG		
- 330	± 60	SH		
- 470	± 60	TH		
- 750	± 120	UJ		
- 1 000	± 250	QK		

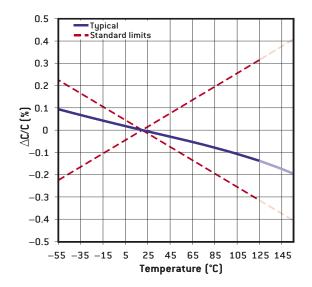


General Information NPO/COG (Class 1)

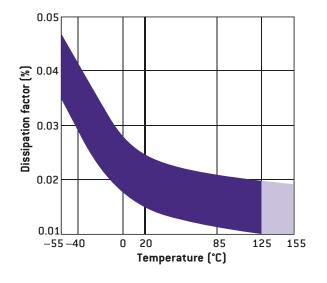
IMPEDANCE VERSUS FREQUENCY



CAPACITANCE CHANGE VERSUS TEMPERATURE

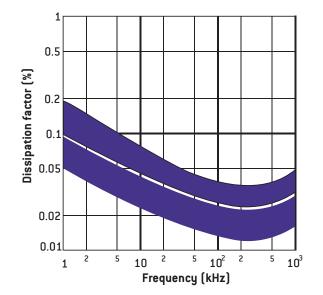


DISSIPATION FACTOR VERSUS TEMPERATURE

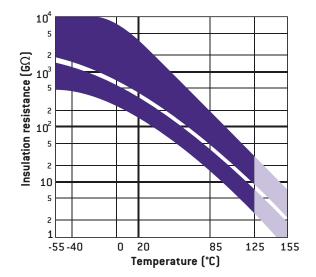


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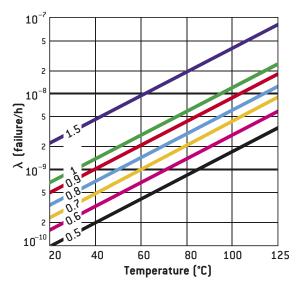
DISSIPATION FACTOR VERSUS FREQUENCY



IR VERSUS TEMPERATURE



TYPICAL FAILURE RATE VERSUS TEMPERATURE



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General Information X7R (Class 2)

COMPOSITION

Class 2 capacitors are produced by using a dielectric made of barium titanate (Ba Ti 0_3). By nature, the dielectric is a ferroelectric compound with a high dielectric constant usually varying :

- from 1 000 to 5 000 typical of capacitors meeting 2C1 type specifications (BX, X7R),
- from 5 000 to 15 000 typical of capacitors meeting Z5U or Y5V type specifications.

Depending on whether the dielectric contains a flux additive, mainly bismuth or boron, electrodes are made of Ag-Pd alloys with high silver content or high palladium content, even pure palladium in some cases.

STABILITY

As the dielectric is a ferro-electric material, class 2 capacitors present significant variations under such stresses as :

- temperature,
- voltage,
- frequency.

In addition, the dielectric absorption coefficient can reach a few % and piezo-electric phenomena can affect the dielectric at critical frequencies (full information and specific documents available on request).

MECHANICAL PROPERTIES

Class 2 dielectrics are hard materials and are sensitive to thermo-mechanical stress. Stress should be limited when mounting and adequate substrates with an adapted expansion coefficient used.

BISMUTH OR BISMUTH FREE DIELECTRICS

Class 2 capacitors are made of ceramics capable to embed a flux element (e.g. bismuth or boron salt). Their eventual use will affect the choice of electrode alloys firing temperature used. Capacitor behavior under such constraints as temperature, voltage, frequency and even reliability, in some applications (further information available on request), is also different.

That is why French and European standard authorities have decided to differentiate bismuth from bismuth free ceramics by measuring tangent δ at -55° C. Tangent Tg δ (-55° C) 350.10^{-4} in flux free dielectrics.

Flux free dielectrics are identified by suffix «A» after capacitor type (e.g. CNC2A).

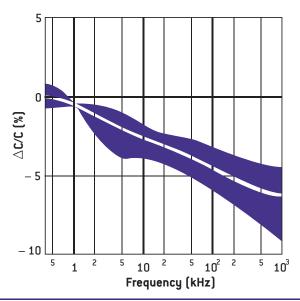
CAPACITANCE/TEMPERATURE RELATIONSHIP

Capacitance variations are defined within a specified temperature range, + 20°C being the reference temperature. This characteristic is expressed by associating the temperature range and capacitance stability.

Stability category	Max. capacitance variation (%) with reference to capacitance at 20°C					
Code letter	Without voltage	At rated DC voltage (U _{DC})				
В	±10	+ 10- 15				
С	± 20	+ 20 - 30				
D	+ 20 - 30	+ 20 - 40				
E	+ 20 – 55	+ 20 - 65				
R	+ 15 - 15	Not applicable				
х	+ 15 – 15	+ 15 – 25				

Temperature category							
Code	Temperature range						
1	– 55°C +125°C						
2	– 55°C + 85°C						
4	– 25°C + 85°C						

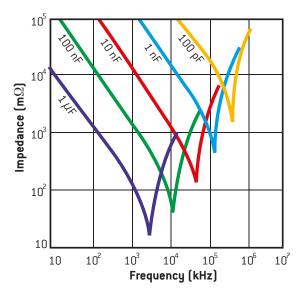
CAPACITANCE CHANGE VERSUS FREQUENCY



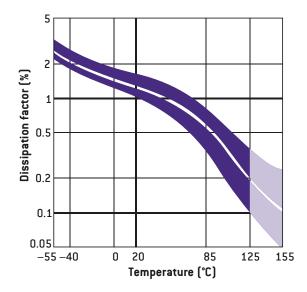


General Information X7R (Class 2)

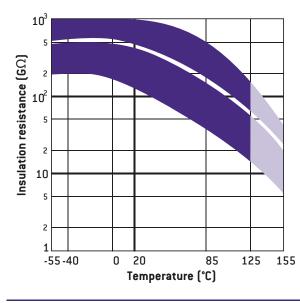
IMPEDANCE VERSUS FREQUENCY



DISSIPATION FACTOR VERSUS TEMPERATURE

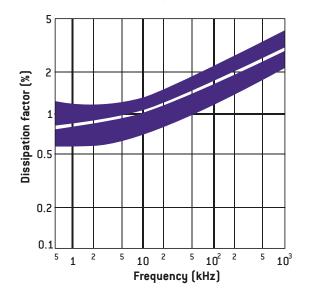


IR VERSUS TEMPERATURE

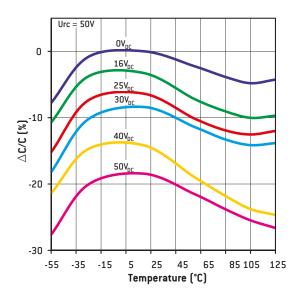


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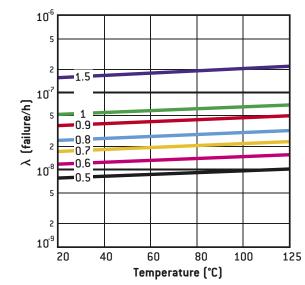
DISSIPATION FACTOR VERSUS FREQUENCY



CAPACITANCE CHANGE VERSUS TEMPERATURE



TYPICAL FAILURE RATE VERSUS TEMPERATURE

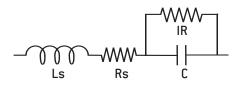


Ceramic Capacitors Technology

MLCC STRUCTURE

EQUIVALENT CIRCUIT

Capacitor is a complex component combining resistive, inductive and capacitive phenomena. A simplified schematic for the equivalent circuit is:



DIELECTRIC CHARACTERISTICS

Insulation Resistance (IR) is the resistance measured under DC voltage across the terminals of the capacitor and consists principally of the parallel resistance shown in the equivalent circuit. As capacitance values and hence the area of dielectric increases, the IR decreases and hence the product (C x IR) is often specified in Ω .F or M Ω .µF.

The Equivalent Series Resistance (ESR) is the sum of the resistive terms which generate heating when capacitor is used under AC voltage at a given frequency (f).

Dissipation factor (DF) is the ration of the apparent power input will turn to heat in the capacitor:

$\mathrm{DF} = 2\pi\,\mathrm{f}\,\mathrm{C}\,\mathrm{ESR}$

When a capacitor works under AC voltage, **heat power loss (P)**, expressed in Watt, is equal to:

 $P = 2\pi f C Vrms^2 DF$

The series inductance (Ls) is due to the currents running through the electrodes. It can distort the operation of the capacitor at high frequency where the impedance (Z) is given as:

Z = Rs + j (Ls. ω - 1/(C. ω)) with ω = 2 π f

When frequency rises, the capacitive component of capacitors is gradually canceled up to the resonance frequency, where :

Z = Rs and LsC. ω^2 = 1

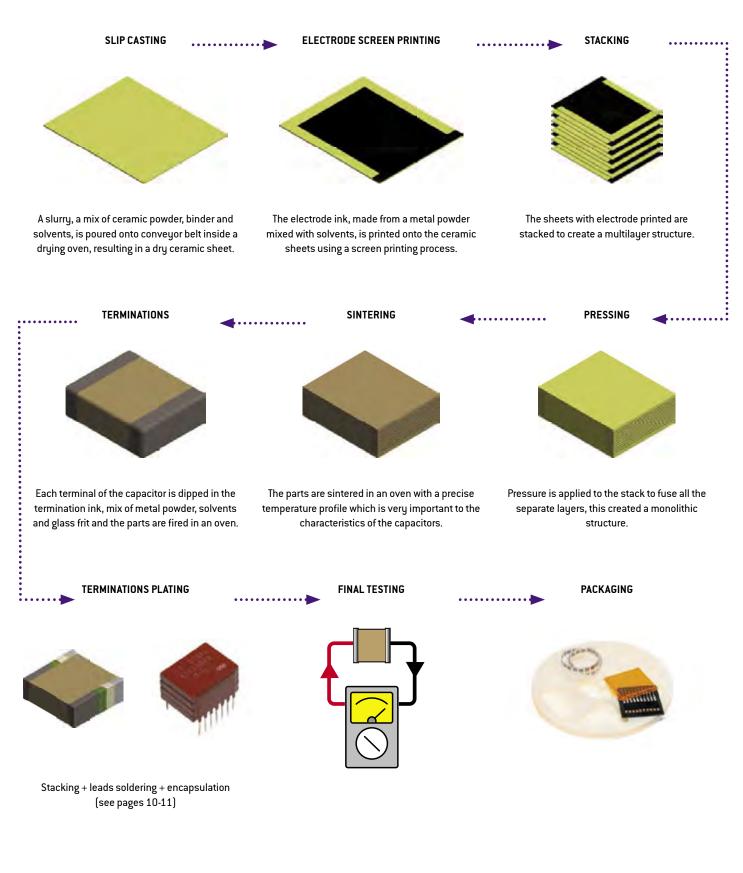
Above this frequency the capacitor behaves like an inductor.

	P100	NPO	N2200 (C4xx)	BX	2C1	X7R	
Dielectric material	Porcelain	Magnesium titanate or Neodynium baryum titanate	Barium zirconate titanate	Baryum titanate (BaTiO ₃)		0 ₃)	
Dielectric constant	15 – 18	20 – 85	450	2,000 – 5,000			
Electrode technology	PME (Precious Metal Electrodes): Ag/Pd						
Capacitance variation between —55°C and +125/°C without DC voltage	(400,20) #6	(0.20) #6	(-2,200±500) ppm/°C	±15%	±20%	±15%	
Capacitance variation between -55°C and +125/°C with DC rated voltage	- (100±30)ppm/°C	(0±30)ppm/°C	0 -15%	15%-25%	20% -30%	Not applicable	
Piezo-electric effect		None	None	Yes			
Dielectric absorption		None	Few %	Few %			
Thermal shock sensitive		+	+	++			



Ceramic Capacitors Technology

MANUFACTURING STEPS





SMD TERMINATIONS

						R	ecommended r	nounting proce	ss		
NON RoHS Compliant	Code	RoHS COMPLIANT	Code	Magnetic	Epoxy bonding	lron soldering	Wave soldering	Vapor phase soldering	Infrared soldering	Wire bonding	Storage (months)*
Ag	Q	Ag	QW / P	No	•	•	•	•			18
Ag/Pd/Pt	-	Ag/Pd/Pt	W/A	No	•	•	•				24
Ag/Pd/Pt + dipped Sn/Pb 60/40	н	Ag/Pd/Pt + dipped Sn	нพ	No		•					24
Ag + Ni + electrolytic Sn/Pb 95/5	С	Ag + Ni + electrolytic Sn	CW/S	Yes		•	•	•	•		18
Ag + Ni + electrolytic Sn/Pb 60/40	D	-	-	Yes		•	•	•	•		18
-	-	Ag + Cu + electrolytic Sn	C**	No		•	•	•	•		18
Ag + Ni + dipped Sn/Pb 60/40	E	-	-	Yes		•	•				24
Ag + Ni + Au	G	Ag + Ni + Au	GW	Yes	•	•	•	•	•	•	36
Ag + Polymer + Ni + Sn/Pb 95/5	YC	Ag + Polymer + Ni + Sn	YCW	Yes		•	•	•	•		18
Ag + Polymer + Ni + Sn/Pb 60/40	YD	-	-	Yes		•	•	•	•		18
Ag + Polymer + Ni + Au	YG	Ag + Polymer + Ni + Au	YGW	Yes	•	•	•	•	•	•	36

Nickel (Ni) or Copper (Cu) barriers amplify thermal shock and are not recommended for chip sizes larger than 3030.

* Storage must be in a dry environment at a temperature of 20°C with a relative humidity below 50%, or preferably in a package enclosing a desiccant.

** Non magnetic chips series only.

SMD ENVIRONMENTAL TESTS

Ceramic chip capacitors for SMD are designed to meet test requirements of CECC 32100 and NF C 93133 standards as specified below in compliance with NF C 20700 and IEC 68 standards:

- Solderability: NF C 20758, 260°C, bath 62/36/2.
- Adherence: 5N force.
- Vibration fatigue test: **NF C 20706,** 20 g, 10 Hz to 2,000 Hz, 12 cycles of 20 minutes each.
- Rapid temperature change: NF C 20714, -55°C to + 125°C, 5 cycles.
- Combined climatic test: IEC 68-2-38.
- Damp heat: NF C 20703, 93 %, H.R., 40°C.
- Endurance test: 1,000 hours, 1.5 U_{RC}, 125°C.

STORAGE OF CHIP CAPACITORS

TINNED OR NON TINNED CHIP CAPACITORS

Storage must be in a dry environment at a temperature of 20°C with a relative humidity below 50 %, or preferably in a packaging enclosing a desiccant.

STORAGE IN INDUSTRIAL ENVIRONMENT:

- 2 years for tin dipped chip capacitors,
- 18 months for tin electroplated chip capacitors,
- 2 years for non tinned chip capacitors,
- 3 years for gold plated chip capacitors.

STORAGE IN CONTROLLED NEUTRAL NITROGEN ENVIRONMENT:

- 4 years for tin dipped or electroplated chip capacitors,
- 4 years for non tinned chip capacitors,
- 5 years for gold plated chip capacitors.

Storage duration should be considered from delivery date and not from batch manufacture date. The tests carried out at final acceptance stage (solderability, susceptibility to solder heat) enable to assess the compatibility to surface mounting of the chips.



GENERAL INFORMATION

LEAD STYLES

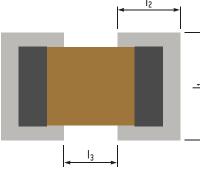


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SOLDERING ADVICES FOR REFLOW SOLDER-

ING



Large chips above size 2225 are not recommended to be mounted on epoxy board due to thermal expansion coefficient mismatch between ceramic capacitor and epoxy. Where larger sizes are required, it is recommended to use components with ribbon or other adapted leads so as to absorb thermo-mechanical strains.

RECOMMENDED FOOTPRINT FOR SMD CAPACITORS

Ceramic is by nature a material which is sensitive both thermally and mechanically. Stresses caused by the physical and thermal properties of the capacitors, substrates and solders are attenuated by the leads.

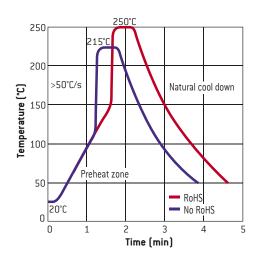
Wave soldering is unsuitable for sizes larger than 2220 and for the higher ends of capacitance ranges due to possible thermal shock (capacitance values given upon request).

Dimensions			Reflow s	oldering			Wave soldering					
in inches (in mm)			3	I ₁		l ₂		l ₃				
0402	0.043	(1.1)	0.035	(0.9)	0.012	(0.3)	0.043	(1.1)	0.047	(1.2)	0.012	(0.3)
0403	0.055	(1.4)	0.035	(0.9)	0.012	(0.3)	0.055	(1.4)	0.047	(1.2)	0.012	(0.3)
0504	0.063	(1.6)	0.051	(1.3)	0.016	(0.4)	0.063	(1.6)	0.063	(1.6)	0.016	(0.4)
0603	0.055	(1.4)	0.059	(1.5)	0.02	(0.5)	0.055	(1.4)	0.071	(1.8)	0.02	(0.5)
0805	0.073	(1.85)	0.065	(1.65)	0.024	(0.6)	0.073	(1.85)	0.077	(1.95)	0.024	(0.6)
0907	0.094	(2.4)	0.065	(1.65)	0.035	(0.9)	0.094	(2.4)	0.077	(1.95)	0.035	(0.9)
1005	0.073	(1.85)	0.067	(1.7)	0.039	(1)	0.073	(1.85)	0.079	[2]	0.039	[1]
1206	0.083	(2.1)	0.067	(1.7)	0.059	(1.5)	0.083	(2.1)	0.079	(2)	0.059	(1.5)
1210	0.118	(3)	0.069	(1.75)	0.059	(1.5)	0.118	(3)	0.081	(2.05)	0.059	(1.5)
1605	0.073	(1.85)	0.071	(1.8)	0.087	(2.2)	0.073	(1.85)	0.083	(2.1)	0.087	(2.2)
1806	0.087	(2.2)	0.073	(1.85)	0.102	(2.6)	0.087	(2.2)	0.085	(2.15)	0.102	(2.6)
1812	0.152	(3.85)	0.073	(1.85)	0.102	(2.6)	0.152	(3.85)	0.085	(2.15)	0.102	(2.6)
1825	0.281	(7.15)	0.073	(1.85)	0.102	(2.6)	0.281	(7.15)	0.085	(2.15)	0.102	(2.6)
2210	0.13	(3.3)	0.079	(2)	0.146	(3.7)	0.13	(3.3)	0.091	(2.3)	0.146	(3.7)
2220	0.228	(5.8)	0.079	(2)	0.146	(3.7)	0.228	(5.8)	0.091	(2.3)	0.146	(3.7)
2225	0.281	(7.15)	0.079	(2)	0.146	(3.7)	0.281	(7.15)	0.091	(2.3)	0.146	(3.7)

Infrared and vapor phase reflow, are preferred for high reliability applications as inherent thermo-mechanical strains are lower than those inherent to wave soldering.

Whatever the soldering process is, it is highly recommended to apply a thermal cycle, see hereafter our recommended soldering profile:

RECOMMENDED VAPOR PHASE REFLOW PROFILE



RECOMMENDED IR REFLOW PROFIL

215°C-225°C

250

200

150

100

50

0

0

20°C

1

2

emperature (°C)

245°C-255°C

RoHS

3

Time (min)

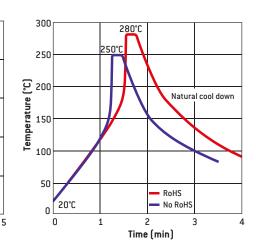
No RoHS

4

Natural

cool down

RECOMMENDED WAVE SOLDERING PROFILE



SOLDERING ADVICES FOR IRON SOLDERING

Attachment with a soldering iron is discouraged due to ceramic brittleness and the process control limitations. In the event that a soldering iron must be used, the following precautions should be observed:

- Use a substrate with chip footprints big enough to allow putting side by side one end of the capacitor and the iron tip without any contact between this tip and the component,
- place the capacitor on this footprint,

- heat the substrate until the capacitor's temperature reaches 150°C minimum (preheating step, maximum 1°C per second),
 - place the hot iron tip (a flat tip is preferred) on the footprint without touching the capacitor. Use a regulated iron with a 30 watts maximum power. The recommended temperature of the iron is 270 ±10°C. The temperature gap between the capacitor and the iron tip must not exceed 120°C,



- leave the tip on the footprint for a few seconds in order to increase locally the footprint's temperature,
- use a cored wire solder and put it down on the iron tip. In a preferred way use Sn/Pb/Ag 62/36/2 alloy,
- wait until the solder fillet is formed on the capacitor's termination,
- take away iron and wire solder,
- wait a few minutes so that the substrate and capacitor come back down to

PACKAGING

TAPE AND REEL

The films used on the reels correspond to standard IEC 60286-3. Films are delivered on reels in compliance with document IEC 286-3 dated 1991.

Minimum quantity is 250 chips.

Maximum quantities per reel are as follows:

- Super 8 reel 0 180: 2,500 chips.
- Super 8 reel 0 330: 10,000 chips.
- Super 12 reel 0 180: 1,000 chips.

Reel marking complies with CECC 32100 standard:

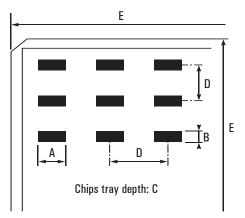
- Model.
- Rated capacitance.
- Capacitance tolerance.
- Rated voltage.
- Batch number.

DIMENSIONAL CHARACTERISTICS OF CHIPS TRAY PACKAGES

the preheating temperature,

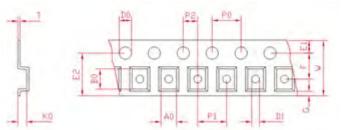
- solder the second termination using the same procedure as the first,
- let the soldered component cool down slowly to avoid any thermal shock.

TRAY PACKAGES



C!	Nr. of chips/	Oriente distinc		Dim	Dimensions in inches (in mm)						
Sizes	package	Oriented chips	Α	В	C	D	E				
0402	100	No	0 0.112	2 (0 3.02)	0.065 (1.65)	0.167 (4.24)	2 (50.8)				
0403	100	No	0 0.112	2 (0 3.02)	0.065 (1.65)	0.167 (4.24)	2 (50.8)				
0504	100	Yes	0.059 (1.5)	0.045 (1.14)	0.035 (0.89)	0.167 (4.24)	2 (50.8)				
0603	340	Yes	0.1 (2.54)	0.06 (1.52)	0.045 (1.14)	0.167 (4.24)	2 (50.8)				
0805	100	Yes	0.1 (2.54)	0.06 (1.52)	0.045 (1.14)	0.167 (4.24)	2 (50.8)				
1206	100	No	0.14 (3.56)	0.14 (3.56)	0.06 (1.52)	0.167 (4.24)	2 (50.8)				
1210	100	Yes	0.14 (3.56)	0.14 (3.56)	0.06 (1.52)	0.167 (4.24)	2 (50.8)				
1812	100	No	0.25 (6.35)	0.25 (6.35)	0.13 (3.3)	0.345 (8.76)	4 (101.6)				
1012	25	Yes	0.24 (6.1)	0.265 (6.73)	0.07 (1.78)	0.345 (8.76)	2 (50.8)				
2220	100	Yes	0.25 (6.35)	0.25 (6.35)	0.13 (3.3)	0.345 (8.76)	4 (101.6)				
2220	25	Yes	0.24 (6.1)	0.265 (6.73)	0.07 (1.78)	0.345 (8.76)	2(50.8)				

HIGH Q CAPACITORS TAPE AND REEL PACKAGING SPECIFICATIONS



Sizes	Type (1)	W±0.3 inches (mm)	F ±0.05 inches (mm)	P1 ±0.1 inches (mm)	T max. inches (mm)	Reel Size inches (mm)	Quantity per Reel
A (0505)	Н	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	3'000
A (0505)	V	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	3'000
S (0603)	Н	0,315 (8)	0,138 (3.5)	0,157 (4)	0,016 (0,4)	7,087 (180)	4'000
F (0805)	Н	0,315 (8)	0,138 (3.5)	0,157 (4)	0,016 (0,4)	7,087 (180)	4'000
B (1111)	Н	0,315 (8)	0,138 (3.5)	0,157 (4)	0,012 (0,3)	7,087 (180)	1'000
B (1111)	V	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	1'000
X (2225)	Н	0,472 (12)	0,138 (5.5)	0,472 (12)	0,018 (0,45)	12,992 (330)	500
E (4040)	Н	0,945 (24)	0,453 ^{±0,004} (11.5 ^{±0.1})	0,630 (16)	0,018 (0,45)	12,992 (330)	700
E (4040)	V	1,260 (32)	0,559 ^{±0,004} (14.2 ^{±0.1})	0,945 (24)	0,022 (0,55)	15 (381)	350

(1): Horizontal (H) or Vertical (V) orientation in cavities.



EIA STANDARD CAPACITANCE VALUES

Following EIA standard, the values and multiples that are indicated in the chart below can be ordered. E48, E96 series and intermediary values are available upon request.

E6 (± 20%)	E12 (± 10%)	E24 (± 5%)
	10	10
10	10	11
10	12	12
	12	13
	15	15
15	15	16
15	18	18
	18	20
	22	22
22	22	24
22	27	27
	27	30
	22	33
22	33	36
33		39
	39	43
		47
	47	51
47		56
	56	62
		68
	68	75
68		82
	82	91

Voltage (V)	Code	Letter code
25	250	A
40	400	В
50	500	C
63	630	D
100	101	E
200	201	G
250	251	Н
400	401	К
500	501	L
1,000	102	М
2,000	202	Р
3,000	302	R
4,000	402	S
5,000	502	Т
7,500	752	U
10,000	103	W

PART MARKING TOLERANCE CODES

Letter code

CU

DU

FU F

G

J

Κ

М

Use the following tolerance code chart for part markings:

Tolerance

±0.25pF

±0.5pF

±1pF

±1%

+2%

+5%

±10%

±20%

EIA CAPACITANCE CODE

The capacitance is expressed in three digit codes and in units of pico Farads (pF). The first and second digits are significant figures of the capacitance value and the third digit identifies the multiplier.

For capacitance value < 10pF, R designates a decimal point. See examples below:

EIA code	Capacitance value			
	in pF	in nF	in µF	
2R2	2.2	0.0022	0.0000022	
6R8	6.8	0.0068	0.000068	
220	22	0.022	0.000022	
470	47	0.047	0.000047	
181	180	0.18	0.00018	
221	220	0.22	0.00022	
102	1,000	1	0.001	
272	2,700	2.7	0.0027	
123	12,000	12	0.012	
683	68,000	68	0.068	
124	120,000	120	0.12	
564	560,000	560	0.56	
335	3,300,000	3,300	3.3	
825	8,200,000	8,200	8.2	
156	15,000,000	15,000	15	
686	68,000,000	68,000	68	
107	100,000,000	100,000	100	
227	220,000,000	220,000	220	

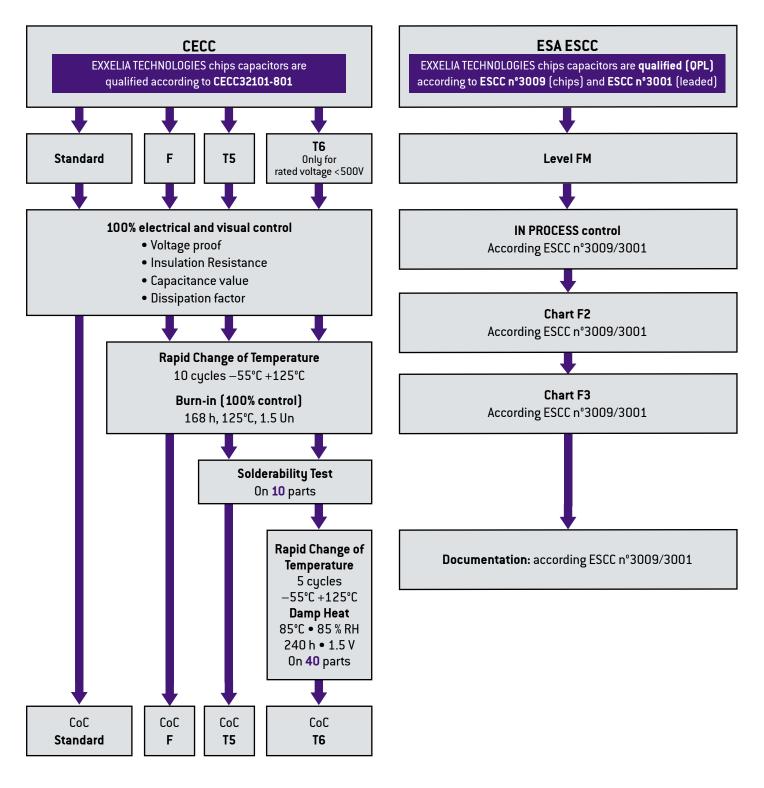
PART MARKING VOLTAGE CODES

Use the following voltage code chart for part markings:



RELIABILITY LEVELS

Exxelia proposes different reliability levels for the ceramic capacitors for both NPO and X7R ceramics.



(E)

EXXELIA

As the world's leading manufacturer of specific passive components, we stand apart through our ability to quickly evaluate the application specific engineering challenges and provide a cost-effective and efficient solutions.

For requirements that cannot be met by catalog products, we offer leading edge solutions in custom configuration: custom geometries, packaging, characteristics, all is possible thanks to our extensive experience and robust development process, while maintaining the highest level of reliability.

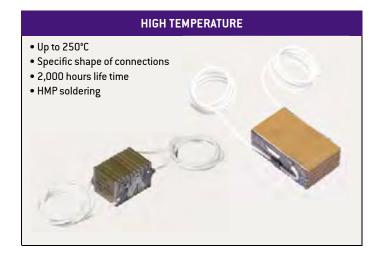
Where necessary, special testing is done to verify requirements, such as low dielectric absorption, ultra-high insulation resistance, low dissipation factor, stability under temperature cycling or under specified environmental conditions, etc.

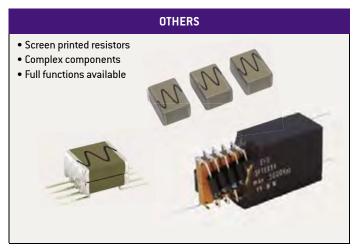
HIGH CAPACITANCE

- High energy density
- Specific case sizes
- Specific shape of connections (high resistance to vibrations)











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General Information

MATERIALS EXPERT

For 50 years and as a market leader, EXXELIA's comprehensive knowledge of the materials properties and performances have enabled us to design capacitors in Porcelain, NPO, BX, 2C1, BP, X7R and -2200ppm/°C ceramics.

CUSTOM DESIGNS

Our catalog products don't meet your application?

Based on the valuable experience accumulated over the design of 2,000+ specific ceramic capacitors, you can trust EXXELIA to define a qualitative custom solution in a time effective manner.

NO OBSOLESCENCE

Choosing a standard or custom EXXELIA product means you won't have to worry about obsolescence.

TYPICAL APPLICATIONS

- Aerospace & Defense: cockpit panels, flight control, radio systems, missile guidance systems...
- Space: military and commercial satellites, launcher...
- Medical: MRI, external defibrillators, implantable devices...
- Telecommunications: base stations...
- Oil and gas: drilling tools, MWD, LWD, wellheads...

ISO 9001 AND AS9100C

Quality is at the core of Exxelia's corporate culture. Each sites has its own certifications.

CERTIFICATIONS

Capacitors manufactured by EXXELIA comply with American and European standards and meet the requirements of many international standards. For Space qualified parts (ESA QPL), please refer to our catalog «Ceramic capacitors for Space applications».

QUALITY & RELIABILITY

EXXELIA is committed to design and manufacture high quality and reliability products. The test cycles reproducing the most adverse operating conditions over extended periods (up to 10 000 hours) have logged to date well over 5.10^9 hours/°Component.

Failure rate data can be provided upon request.

CONFLICT MINERALS

EXXELIA is committed to an approach based on «Conflict Minerals Compliance». This US SEC rule demands complete traceability and a control mechanism for the mineral procurement chain, encouraging importers to buy only «certified» ore.

We have discontinued relations with suppliers that procure from the Democratic Republic of the Congo or an adjoining country.

ENVIRONMENT

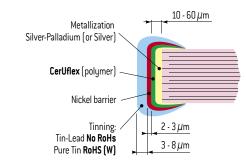
EXXELIA is committed to applying a robust environmental policy, from product design through to shipment. To control its environmental footprint and reconcile this with the company' functional imperatives, our environmental policy provides for the reduction or elimination of hazardous substances. We also focus on compliance with European Union directives and regulations, notably REACH and RoHS.

RoHS COMPLIANCY

SMD CAPACITORS

The capacitor terminations are generally protected by a nickel barrier formed by electrolytic deposit. This barrier gives chip capacitors leaching performance far exceeding the requirements of all applicable standards. The nickel barrier guarantees a minimum resistance to soldering heat for a period of 1 minute at 260°C in a tin-lead (60/40) or tin-lead-silver (62/36/2) bath without noticeable alteration to the solderability. It also allows repeated soldering-unsoldering and the longer soldering times required by reflow techniques.

However nickel barrier amplifies thermal shock and is not recommended for chip sizes equal or greater than CNC Y (30 30) - (C 282 to C 288 - CNC 80 to CNC 94).



LEADED COMPONENTS

As well as for SMD products, leaded capacitors ranges can also be RoHS. These products, which are characterized by the suffix «W» added to the commercial type, are naturally compatible with the soldering alloys used in RoHS mounting technology. The connections coating is generally an alloy SnAg (with a maximum of 4% Ag). However, on a few products that EXXELIA will precise on request, the coating is pure silver.

